FREE

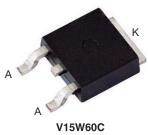


## Vishay General Semiconductor

## **Dual Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.38 \text{ V}$  at  $I_F = 3 \text{ A}$ 

## TMBS<sup>®</sup> TO-252 (D-PAK)





| PRIMARY CHARACTERISTICS                         |                     |  |  |  |  |
|---|---------------------|--|--|--|--|
| I <sub>F(AV)</sub>                              | 2 x 7.5 A           |  |  |  |  |
| $V_{RRM}$                                       | 60 V                |  |  |  |  |
| I <sub>FSM</sub>                                | 90 A                |  |  |  |  |
| $V_F$ at $I_F = 7.5$ A $(T_A = 125  ^{\circ}C)$ | 0.51 V              |  |  |  |  |
| T <sub>J</sub> max.                             | 150 °C              |  |  |  |  |
| Package   | TO-252 (D-PAK)      |  |  |  |  |
| Diode variation                                 | Dual common cathode |  |  |  |  |

#### **FEATURES**

Trench MOS Schottky technology

· Ideal for automated placement

Low forward voltage drop, low power losses
HALOGEN

· High efficiency operation

 Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

 Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-252 (D-PAK)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

| <b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)                       |            |                                   |             |      |  |
|--|------------|-----------------------------------|-------------|------|--|
| PARAMETER  |            | SYMBOL                            | V15W60C     | UNIT |  |
| Maximum repetitive peak reverse voltage  |            | V <sub>RRM</sub>                  | 60          | V    |  |
| Maximum average forward rectified current (fig. 1)   | per device | I <sub>F(AV)</sub>                | 15          | А    |  |
|  | per diode  |                                   | 7.5         |      |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode |            | I <sub>FSM</sub>                  | 90          | А    |  |
| Operating junction and storage temperature range   |            | T <sub>J</sub> , T <sub>STG</sub> | -40 to +150 | °C   |  |



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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                        |                         |                               |      |      |      |
|---|------------------------|-------------------------|-------------------------------|------|------|------|
| PARAMETER   | TEST CONDITIONS        |                         | SYMBOL                        | TYP. | MAX. | UNIT |
| Instantaneous forward voltage per diode   | I <sub>F</sub> = 3 A   | T <sub>A</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | 0.47 | -    | V    |
|   | I <sub>F</sub> = 7.5 A |                         |                               | 0.56 | 0.65 |      |
|   | I <sub>F</sub> = 3 A   | T <sub>A</sub> = 125 °C |                               | 0.38 | -    |      |
|   | I <sub>F</sub> = 7.5 A |                         |                               | 0.51 | 0.63 |      |
| Reverse current per diode   | V <sub>R</sub> = 60 V  | T <sub>A</sub> = 25 °C  | I <sub>R</sub> <sup>(2)</sup> | -    | 3500 | μA   |
|   | v <sub>R</sub> = 60 v  | T <sub>A</sub> = 125 °C |                               | 9    | 27   | mA   |

#### **Notes**

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |            |                          |         |      |
|---|------------|--------------------------|---------|------|
| PARAMETER   |            | SYMBOL                   | V15W60C | UNIT |
|   | per diode  | $R_{	heta JC}$           | 2.8     | °C/W |
| Typical thermal resistance  | per device |                          | 1.4     |      |
|   | per device | R <sub>0</sub> JA (1)(2) | 65      |      |

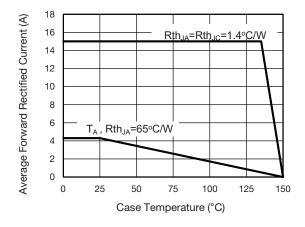
#### **Notes**

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta,JA}$ 

(2) Free air, without heatsink

| ORDERING INFORMATION (Example) |   |   |           |                                    |  |  |  |
|--------------------------------|---|---|-----------|------------------------------------|--|--|--|
| PREFERRED P/N                  | REFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY MODE |   |           |                                    |  |  |  |
| V15W60C-M3/I                   | 0.38  | I | 2500/reel | 13" diameter plastic tape and reel |  |  |  |

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)





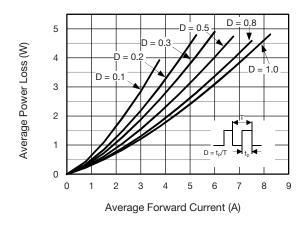


Fig. 2 - Forward Power Loss Characteristics Per Diode



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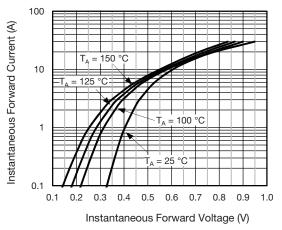


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

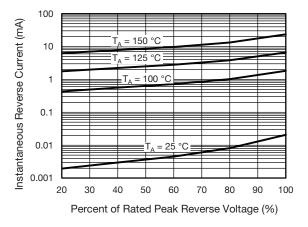


Fig. 4 - Typical Reverse Characteristics Per Diode

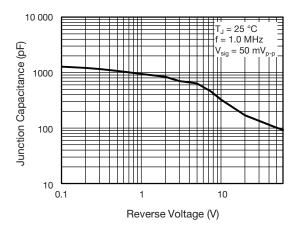


Fig. 5 - Typical Junction Capacitance Per Diode

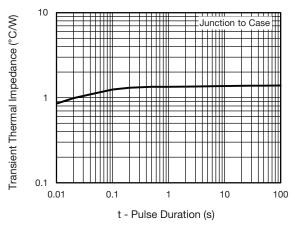
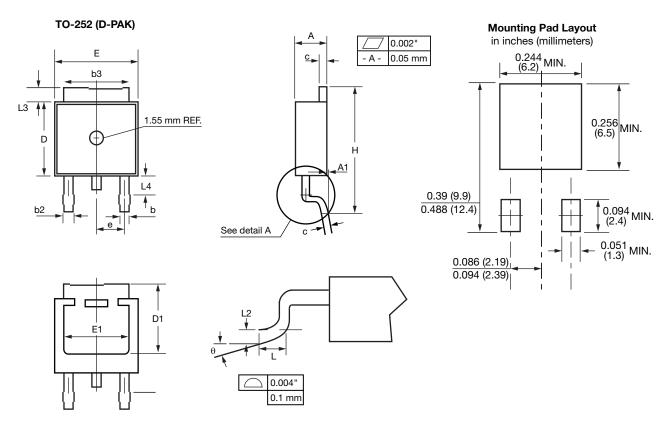


Fig. 6 - Typical Transient Thermal Impedance Per Device



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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



| CVMDOL | INC   | CHES       | MILLIMETERS |       |  |
|--------|-------|------------|-------------|-------|--|
| SYMBOL | MIN.  | MAX.       | MIN.        | MAX.  |  |
| A      | 0.086 | 0.094      | 2.19        | 2.38  |  |
| A1     | -     | 0.005      | -           | 0.13  |  |
| b      | 0.025 | 0.035      | 0.64        | 0.89  |  |
| b2     | 0.033 | 0.045      | 0.84        | 1.14  |  |
| b3     | 0.205 | 0.215      | 5.21        | 5.46  |  |
| С      | 0.018 | 0.024      | 0.46        | 0.61  |  |
| D      | 0.235 | 0.250      | 5.97        | 6.22  |  |
| D1     | 0.205 | -          | 5.21        | -     |  |
| Е      | 0.250 | 0.265      | 6.35        | 6.73  |  |
| E1     | 0.190 | -          | 4.83        | -     |  |
| е      | 0.09  | 0 BSC.     | 2.29 BSC.   |       |  |
| Н      | 0.380 | 0.410      | 9.65        | 10.41 |  |
| L      | 0.055 | 0.070      | 1.40        | 1.78  |  |
| L2     | 0.02  | 0.020 BSC. |             | BSC.  |  |
| L3     | 0.035 | 0.050      | 0.89        | 1.27  |  |
| L4     | 0.025 | 0.039      | 0.64        | 1.01  |  |
| θ      | 0°    | 8°         | 0°          | 8°    |  |

#### Note

<sup>•</sup> Conforms to JEDEC TO-252 variation AA except dimension "D"



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